ANALOG DEVICES

LC²MOS Octal 8-Bit D/A Converter

AD7228

1.1 Scope.

This specification covers the detail requirements for an octal CMOS digital-to-analog converter.

1.2 Part Number.

The complete part number per Table 1 of this specification is as follows:

Device	Part Number[1]
−1	AD7228T(X)/883B
−2	AD7228U(X)/883B

NOTE
[1]To complete the part number substitute the package identifier as shown in paragraph 1.2.3.

1.2.3 Case Outline.

See Appendix 1 of General Specification ADI-M-1000: package outline:

(X)	Package	Description
Q	Q-24	24-Pin Cerdip, 0.3" Width
E	E-28A	28-Contact LCC

1.3 Absolute Maximum Ratings. (T_A = +25°C unless otherwise noted)

V_{DD} to GND	−0.3 V to +17 V
V_{DD} to V_{SS}	+0.3 V to +24 V
Digital Input Voltage	−0.3 V, V_{DD}
V_{REF} to GND	−0.3 V, V_{DD}
V_{OUT} to GND[1]	V_{SS}, V_{DD}
Power Dissipation	
Up to +75°C	1000 mW
Derates above +75°C	2.0 mW/°C
Operating Temperature Range	−55°C to +125°C
Thermal Resistance (θ_{JC}):	
Case 1 (Q-24)	See MIL-M-38510, Appendix C
Case 3 (E-28A)	See MIL-M-38510, Appendix C
Storage Temperature	−65°C to +125°C
Lead Temperature (Soldering 10 sec)	+300°C
Junction Temperature	+175°C

NOTE
[1]Outputs may be shorted to any voltage in the range V_{SS} to V_{DD} provided that the power dissipation of the package is not exceeded. Typical short circuit for a short to V_{SS} is 50 mA.

AD7228—SPECIFICATIONS

Table 1.

Test	Symbol	Device	Design Min	Design Max	Sub Group	Test Condition[1]	Units
Total Unadjusted Error[2]	TUE	−1, 2	−2	+2	1	V_{DD} = 15 V ±10%, V_{REF} = +10 V (Single Supply Only)	LSB
		−1	−2	+2	2, 3		
		−2	−1	+1	2, 3		
		−2	−1	+1	4		
Total Unadjusted Error	TUE	−1	−2	+2	13, 14, 15	Dual Supply Only	LSB
		−2	−1	+1			
Relative Accuracy	RA	−1, 2	−1	+1	1		LSB
		−1	−1	+1	2, 3		
		−2	−0.5	+0.5	2, 3		
		−2	−0.5	+0.5	12		
Differential Nonlinearity	DNL	−1, 2	−1	+1	1, 2, 3	Guaranteed Monotonic (Single Supply Only)	LSB
Differential Nonlinearity	DNL	−1, 2	−1	+1	13, 14, 15	Dual Supply Only	LSB
Full-Scale Error[3]	A_E	−1, 2	−1	+1	1		mV
		−1	−1	+1	2, 3		
		−2	−0.5	+0.5	2, 3		
		−2	−0.5	+0.5	12		
Zero Code Error	A_{ZCE}	−1, 2	−25	+25	1		mV
		−1	−30	+30	2, 3		
		−2	−20	+20	2, 3		
		−2	−15	+15	12		
Load Resistance	R_L	−1, 2	2		1, 2, 3	V_{OUT} = ±10 V (Dual Supply & Single Supply)	kΩ
Reference Input Voltage Range	V_{REF}	−1, 2	2	10	1, 2, 3		V
Reference Input Resistance	R_{IN}	−1, 2	2		1, 2, 3	Dual Supply Only	kΩ
Reference Input Capacitance[4]	C_{IN} (REF)	−1, 2		500	13, 14, 15	Dual and Single Supply	pF
Digital Input High Voltage	V_{INH}	−1, 2	2.4		1, 2, 3	Dual Supply Only	V
Digital Input Low Voltage	V_{INL}	−1, 2		0.8	1, 2, 3	Input Coding Is Binary	V
Digital Input Leakage Current	I_{ILC}	−1, 2	−1	+1	1, 2, 3		μA
Digital Input Capacitance	C_{IN}	−1, 2		8	13, 14, 15		pF
Voltage Output Slew Rate	SR	−1, 2	2		13, 14, 15	Dual and Single Supply	V/μs
Voltage Output Settling Time[5] Positive Full-Scale Change	t_{SL}	−1, 2		5	13, 14, 15	Dual and Single Supply	μs
Negative Full-Scale Change		−1, 2		5		Dual Supply	
				7		Single Supply	
Power Supply Current	I_{DD}	−1, 2		16	1	Dual Supply Only	mA
				22	2, 3		
	I_{SS}	−1, 2		14	1		
				20	2, 3		
Function Tests[6]		−1, 2			7		
Address to $\overline{WR}$ Setup Time	t_1	−1, 2	0		9, 10, 11	Dual and Single Supply See Figure 2 and Note 7	ns
Address to $\overline{WR}$ Hold Time	t_2	−1, 2	0		9, 10, 11		
Data Valid to $\overline{WR}$ Setup Time	t_3	−1, 2	70		9		
			100		10, 11		
Data Valid to $\overline{WR}$ Hold Time	t_4	−1, 2	10		9, 10, 11		ns

Test	Symbol	Device	Design Min	Design Max	Sub Group	Test Condition[1]	Units
Write Pulse Width	t_5	−1, 2	95		9		ns
			150		10, 11		

NOTES
[1] $-55°C < T_A < +125°C$, Dual Supply unless otherwise specified. R_L = 2k, C_L = 100 pF unless otherwise stated. Parameters in subgroups 13, 14, 15 are characterized at initial design and after any subsequent redesigns.
[2] Includes zero code error, relative accuracy and full-scale error.
[3] Calculated after zero code error has been adjusted out.
[4] Occurs when each DAC is loaded with all 1s.
[5] V_{REF} = +10 V; settling time to ±1/2 LSB.
[6] Subgroup 7 tests are for the purpose of verifying the truth table.
[7] All input rise and fall times measured from 10% to 90% of +5 V, $t_R = t_F$ = 5 ns.
Timing measurement reference level is $\frac{V_{INH} + V_{INL}}{2}$.

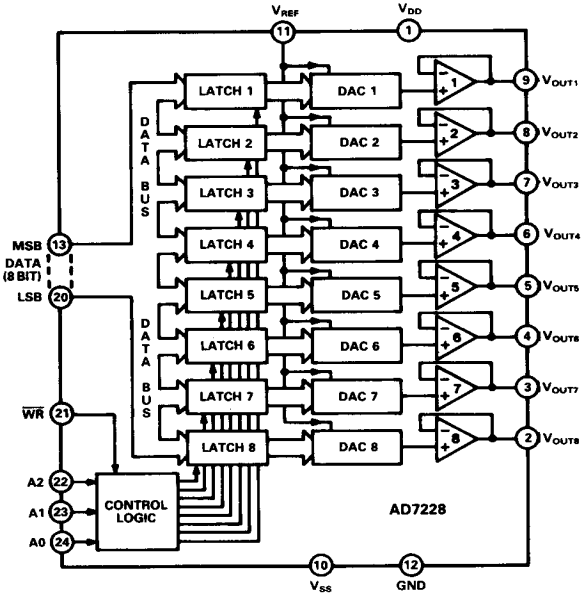
1.3.1 Recommended Operating Conditions.

Operating Voltage Range for Dual Supply
- Positive Supply (V_{DD}) . . . . . +10.8 V to +16.5 V
- Negative Supply (V_{SS}) . . . . . −4.5 V to −5.5 V
- Reference Voltage (V_{REF})[1] . . . . . +2.0 V to +10.0 V

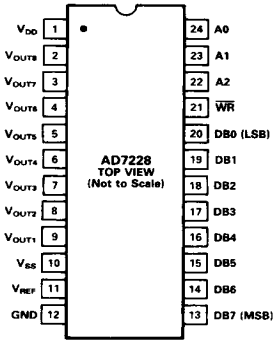
Operating Voltage Range for Single Supply
- Positive Supply (V_{DD}) . . . . . +13.5 V to +16.5 V
- Negative Supply (V_{SS}) . . . . . 0 V
- Reference Voltage (V_{REF})[1] . . . . . +10 V

NOTE
[1] V_{OUT} must be less than V_{DD} by 3.5 V to ensure correct operation.

3.2.1 Functional Block Diagram and Terminal Assignments.



Q Package (Cerdip)



E Package (LCC)

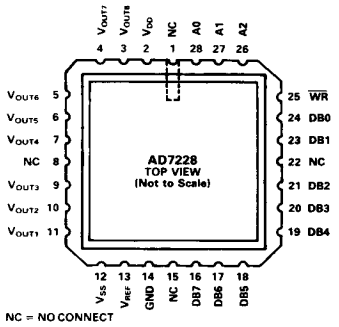


Table 2. Truth Table

AD7228 Control Inputs

$\overline{WR}$	A2	A1	A0	Operation
H	X	X	X	No Operation Device Not Selected
L	L	L	L	DAC 1 Transparent
	L	L	L	DAC 1 Latched
L	L	L	H	DAC 2 Transparent
L	L	H	L	DAC 3 Transparent
L	L	H	H	DAC 4 Transparent
L	H	L	L	DAC 5 Transparent
L	H	L	H	DAC 6 Transparent
L	H	H	L	DAC 7 Transparent
L	H	H	H	DAC 8 Transparent

H = High State L = Low State X = Don't Care

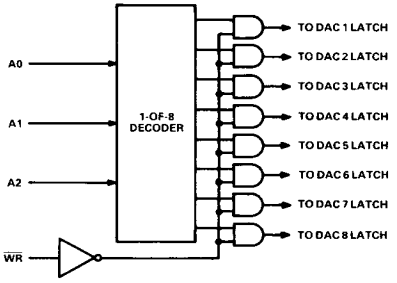


Figure 1. Input Control Logic

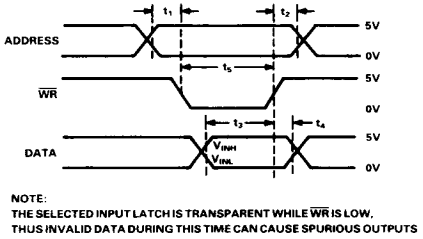


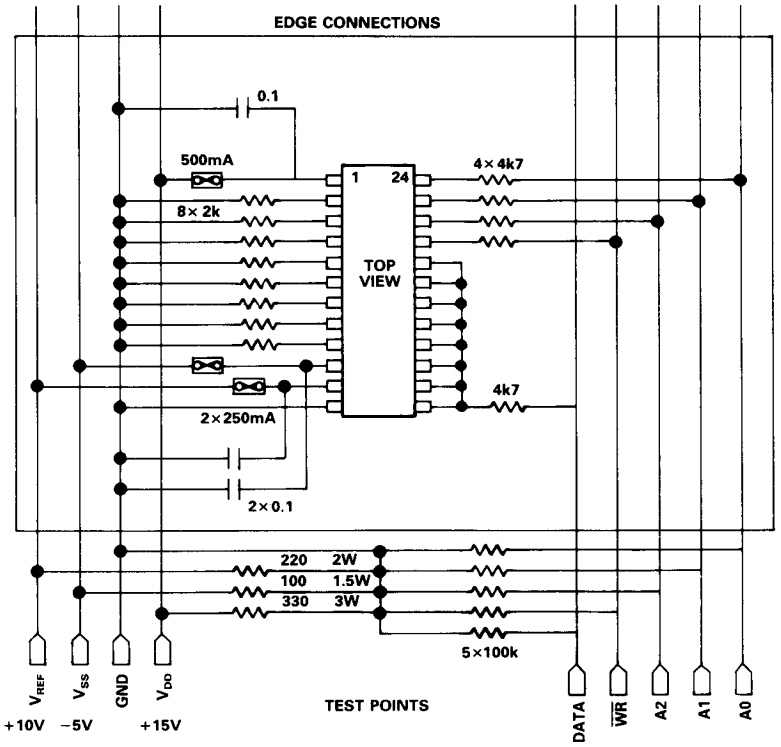
Figure 2. Write Cycle Timing Diagram

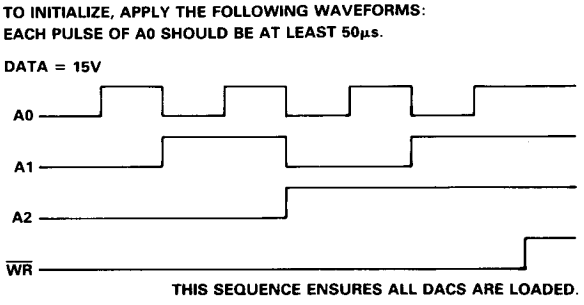
3.2.4 Microcircuit Technology Group.

This microcircuit is covered by technology group (80).

4.2.1 Life Test/Burn-In Circuit.

Steady state life test is per MIL-STD-883 Method 1005. Burn-in is per MIL-STD-883 Method 1015 test condition (B).





Burn-In Conditions